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PATENT APPLICATION

NTTE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Ichio YUDASAKA et al.

Group Art Unit: 2812

Application No.: 09/936,041

Examiner:

Angel Roman

Filed: December 18, 2001

Docket No.:

110553

For:

METHOD FOR MANUFACTURING A THIN-FILM TRANSISTOR COMPRISING A

RECOMBINATION CENTER (AS AMENDED)

AMENDMENT UNDER 37 C.F.R. §1.111

Director of the U.S. Patent and Trademark Office Washington, D.C. 20231

Sir:

In reply to the April 2, 2002 Office Action, please amend the above-identified application as follows:

IN THE TITLE:

Please replace the title so that it reads as follows:

METHOD FOR MANUFACTURING A THIN-FILM TRANSISTOR

COMPRISING A RECOMBINATION CENTER.

IN THE CLAIMS:

Please replace claims 1-2 and 7-13 as follows:

The following is a marked-up version of the amended claims:

1. (Twice Amended) A method of manufacturing a thin-film transistor,

comprising:

forming a channel region facing a gate electrode through a gate insulating

film;

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